



Low Capacitance, Low Charge Injection, ±15 V/+12 V *iCMOS*™ Quad SPST Switches

ADG1211/ADG1212/ADG1213

FEATURES

- 1 pF off capacitance
- 2.6 pF on capacitance
- <1 pC charge injection
- 33 V supply range
- 120 Ω on resistance
- Fully specified at ±15 V, +12 V
- No V_L supply required
- 3 V logic-compatible inputs
- Rail-to-rail operation
- 16-lead TSSOP and 16-lead LFCSP
- Typical power consumption: <0.03 μW

APPLICATIONS

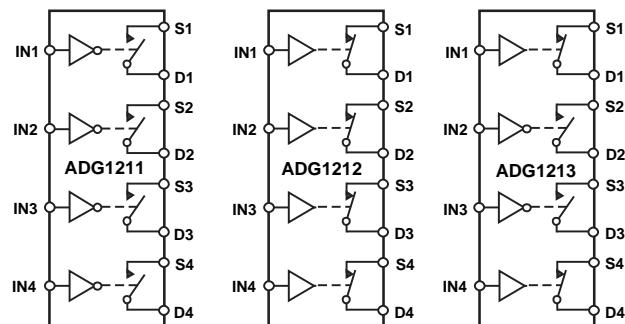
- Automatic test equipment
- Data acquisition systems
- Battery-powered systems
- Sample-and-hold systems
- Audio signal routing
- Video signal routing
- Communication systems

GENERAL DESCRIPTION

The ADG1211/ADG1212/ADG1213 are monolithic complementary metal-oxide semiconductor (CMOS) devices containing four independently selectable switches designed on an *iCMOS* (industrial CMOS) process. *iCMOS* is a modular manufacturing process combining high voltage CMOS and bipolar technologies. It enables the development of a wide range of high performance analog ICs capable of 33 V operation in a footprint that no previous generation of high voltage parts has been able to achieve. Unlike analog ICs using conventional CMOS processes, *iCMOS* components can tolerate high supply voltages while providing increased performance, dramatically lower power consumption, and reduced package size.

The ultralow capacitance and charge injection of these switches make them ideal solutions for data acquisition and sample-and-hold applications, where low glitch and fast settling are required. Fast switching speed coupled with high signal bandwidth make the parts suitable for video signal switching.

FUNCTIONAL BLOCK DIAGRAM



SWITCHES SHOWN FOR A LOGIC 1 INPUT

04778-001

Figure 1.

iCMOS construction ensures ultralow power dissipation, making the parts ideally suited for portable and battery-powered instruments.

The ADG1211/ADG1212/ADG1213 contain four independent single-pole/single-throw (SPST) switches. The ADG1211 and ADG1212 differ only in that the digital control logic is inverted. The ADG1211 switches are turned on with Logic 0 on the appropriate control input, while Logic 1 is required for the ADG1212. The ADG1213 has two switches with digital control logic similar to that of the ADG1211; the logic is inverted on the other two switches. The ADG1213 exhibits break-before-make switching action for use in multiplexer applications.

Each switch conducts equally well in both directions when on and has an input signal range that extends to the supplies. In the off condition, signal levels up to the supplies are blocked.

PRODUCT HIGHLIGHTS

1. Ultralow capacitance.
2. <1 pC charge injection.
3. 3 V logic-compatible digital inputs: $V_{IH} = 2.0$ V, $V_{IL} = 0.8$ V.
4. No V_L logic power supply required.
5. Ultralow power dissipation: <0.03 μW.
6. 16-lead TSSOP and 3 mm × 3 mm LFCSP packages.

Rev. 0

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REVISION HISTORY

7/05—Revision 0: Initial Version

SPECIFICATIONS

DUAL SUPPLY

$V_{DD} = 15 \text{ V} \pm 10\%$, $V_{SS} = -15 \text{ V} \pm 10\%$, GND = 0 V, unless otherwise noted.

Table 1.

Parameter	Y Version ¹			Unit	Test Conditions/Comments
	25°C	-40°C to +85°C	-40°C to +125°C		
ANALOG SWITCH					
Analog Signal Range				V	
On Resistance (R_{ON})	120		V_{DD} to V_{SS}	Ω typ	$V_S = \pm 10 \text{ V}$, $I_S = -1 \text{ mA}$; Figure 20
	190	230	260	Ω max	$V_{DD} = +13.5 \text{ V}$, $V_{SS} = -13.5 \text{ V}$
On Resistance Match Between Channels (ΔR_{ON})	2.5			Ω typ	$V_S = \pm 10 \text{ V}$, $I_S = -1 \text{ mA}$
On Resistance Flatness ($R_{FLAT(ON)}$)	6	10	11	Ω max	
	20			Ω typ	$V_S = -5 \text{ V}/0 \text{ V}/+5 \text{ V}$; $I_S = -1 \text{ mA}$
	57	72	79	Ω max	
LEAKAGE CURRENTS					
Source Off Leakage, I_S (Off)	± 0.02			nA typ	$V_{DD} = +16.5 \text{ V}$, $V_{SS} = -16.5 \text{ V}$
	± 0.1	± 0.6	± 1	nA max	$V_S = \pm 10 \text{ V}$, $V_D = \mp 10 \text{ V}$; Figure 21
Drain Off Leakage, I_D (Off)	± 0.02			nA typ	$V_S = \pm 10 \text{ V}$, $V_D = \mp 10 \text{ V}$; Figure 21
	± 0.1	± 0.6	± 1	nA max	
Channel On Leakage, I_D , I_S (On)	± 0.02			nA typ	$V_S = V_D = \pm 10 \text{ V}$; Figure 22
	± 0.1	± 0.6	± 1	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2.0	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current, I_{INL} or I_{INH}	0.005		± 0.1	μA typ	$V_{IN} = V_{INL}$ or V_{INH}
Digital Input Capacitance, C_{IN}	2.5			μA max	
				pF typ	
DYNAMIC CHARACTERISTICS ²					
t_{ON}	105			ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$
	125	160	185	ns max	$V_S = 10 \text{ V}$; Figure 23
t_{OFF}	40			ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$
	50	60	60	ns max	$V_S = 10 \text{ V}$; Figure 23
Break-Before-Make Time Delay, t_D (ADG1213 Only)	25		10	ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$
				ns min	$V_{S1} = V_{S2} = 10 \text{ V}$; Figure 24
Charge Injection	-0.3			pC typ	$V_S = 0 \text{ V}$, $R_S = 0 \Omega$, $C_L = 1 \text{ nF}$; Figure 25
Off Isolation	80			dB typ	$R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$; Figure 26
Channel-to-Channel Crosstalk	90			dB typ	$R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$; Figure 27
Total Harmonic Distortion + Noise	0.15			% typ	$R_L = 10 \text{ k}\Omega$, 5 V rms, $f = 20 \text{ Hz}$ to 20 kHz
-3 dB Bandwidth	1000			MHz typ	$R_L = 50 \Omega$, $C_L = 5 \text{ pF}$; Figure 28
C_S (Off)	0.9			pF typ	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$
	1.1			pF max	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$
C_D (Off)	1			pF typ	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$
	1.2			pF max	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$
C_D , C_S (On)	2.6			pF typ	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$
	3			pF max	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$

ADG1211/ADG1212/ADG1213

Parameter	25°C	Y Version ¹		Unit	Test Conditions/Comments
		-40°C to +85°C	-40°C to +125°C		
POWER REQUIREMENTS					
I _{DD}	0.001		1.0	µA typ	V _{DD} = +16.5 V, V _{SS} = -16.5 V Digital inputs = 0 V or V _{DD}
I _{DD}	220		320	µA max	Digital inputs = 5 V
I _{SS}	0.001		1.0	µA typ	Digital inputs = 0 V or V _{DD}
I _{SS}	0.001		1.0	µA max	Digital inputs = 5 V

¹ Temperature range for Y version is -40°C to +125°C.

² Guaranteed by design, not subject to production test.

SINGLE SUPPLY

$V_{DD} = 12 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, $GND = 0 \text{ V}$, unless otherwise noted.

Table 2.

Parameter	Y Version¹			Unit	Test Conditions/Comments
	25°C	-40°C to +85°C	-40°C to +125°C		
ANALOG SWITCH					
Analog Signal Range			0 V to V_{DD}	V	
On Resistance (R_{ON})	300			Ω typ	$V_S = 0 \text{ V}$ to 10 V, $I_S = -1 \text{ mA}$; Figure 20
	475	567	625	Ω max	$V_{DD} = 10.8 \text{ V}$, $V_{SS} = 0 \text{ V}$
On Resistance Match Between Channels (ΔR_{ON})	4.5			Ω typ	$V_S = 0 \text{ V}$ to 10 V, $I_S = -1 \text{ mA}$
	12	26	27	Ω max	
On Resistance Flatness ($R_{FLAT(ON)}$)	60			Ω typ	$V_S = 3 \text{ V}/6 \text{ V}/9 \text{ V}$, $I_S = -1 \text{ mA}$
LEAKAGE CURRENTS					
Source Off Leakage, I_S (Off)	± 0.02			nA typ	$V_{DD} = 13.2 \text{ V}$, $V_{SS} = 0 \text{ V}$
	± 0.1	± 0.6	± 1	nA max	$V_S = 1 \text{ V}/10 \text{ V}$, $V_D = 10 \text{ V}/1 \text{ V}$; Figure 21
Drain Off Leakage, I_D (Off)	± 0.02			nA typ	
	± 0.1	± 0.6	± 1	nA max	$V_S = 1 \text{ V}/10 \text{ V}$, $V_D = 10 \text{ V}/1 \text{ V}$; Figure 21
Channel On Leakage, I_D , I_S (On)	± 0.02			nA typ	$V_S = V_D = 1 \text{ V}$ or 10 V; Figure 22
	± 0.1	± 0.6	± 1	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2.0	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current, I_{INL} or I_{INH}	0.001		± 0.1	μA typ	$V_{IN} = V_{INL}$ or V_{INH}
Digital Input Capacitance, C_{IN}	3			μA max	
				pF typ	
DYNAMIC CHARACTERISTICS ²					
t_{ON}	120			ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$
	155	190	225	ns max	$V_S = 8 \text{ V}$; Figure 23
t_{OFF}	45			ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$
	65	75	85	ns max	$V_S = 8 \text{ V}$; Figure 23
Break-Before-Make Time Delay, t_D (ADG1213 Only)	50		10	ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$
				ns min	$V_{S1} = V_{S2} = 8 \text{ V}$; Figure 24
Charge Injection	0			pC typ	$V_S = 6 \text{ V}$, $R_S = 0 \Omega$, $C_L = 1 \text{ nF}$; Figure 25
Off Isolation	80			dB typ	$R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$; Figure 26
Channel-to-Channel Crosstalk	90			dB typ	$R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 1 \text{ MHz}$; Figure 27
-3 dB Bandwidth	900			MHz typ	$R_L = 50 \Omega$, $C_L = 5 \text{ pF}$; Figure 28
C_S (Off)	1.2			pF typ	$V_S = 6 \text{ V}$, $f = 1 \text{ MHz}$
	1.4			pF max	$V_S = 6 \text{ V}$, $f = 1 \text{ MHz}$
C_D (Off)	1.3			pF typ	$V_S = 6 \text{ V}$, $f = 1 \text{ MHz}$
	1.5			pF max	$V_S = 6 \text{ V}$, $f = 1 \text{ MHz}$
C_D , C_S (On)	3.2			pF typ	$V_S = 6 \text{ V}$, $f = 1 \text{ MHz}$
	3.9			pF max	$V_S = 6 \text{ V}$, $f = 1 \text{ MHz}$
POWER REQUIREMENTS					
I_{DD}	0.001			μA typ	$V_{DD} = 13.2 \text{ V}$
			1.0	μA max	Digital inputs = 0 V or V_{DD}
I_{DD}	220		320	μA typ	Digital inputs = 5 V
				μA max	

¹ Temperature range for Y version is -40°C to $+125^\circ\text{C}$.

² Guaranteed by design, not subject to production test.

ADG1211/ADG1212/ADG1213

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted.

Table 3.

Parameter	Rating
V _{DD} to V _{SS}	35 V
V _{DD} to GND	-0.3 V to +25 V
V _{SS} to GND	+0.3 V to -25 V
Analog Inputs ¹	V _{SS} – 0.3 V to V _{DD} + 0.3 V or 30 mA, whichever occurs first
Digital Inputs ¹	GND – 0.3 V to V _{DD} + 0.3 V or 30 mA, whichever occurs first
Peak Current, S or D	100 mA (pulsed at 1 ms, 10% duty cycle max)
Continuous Current per Channel, S or D	25 mA
Operating Temperature Range Automotive (Y Version)	-40°C to +125°C
Storage Temperature Range	-65°C to +150°C
Junction Temperature	150°C
16-Lead TSSOP, θ _{JA} Thermal Impedance (4-Layer Board)	112°C/W
16-Lead LFCSP, θ _{JA} Thermal Impedance	72.7°C/W
Reflow Soldering Peak Temperature, Pb free	260°C

¹ Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

Table 4. ADG1211/ADG1212 Truth Table

ADG1211 INx	ADG1212 INx	Switch Condition
0	1	On
1	0	Off

Table 5. ADG1213 Truth Table

ADG1213 INx	Switch 1, 4	Switch 2, 3
0	Off	On
1	On	Off

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

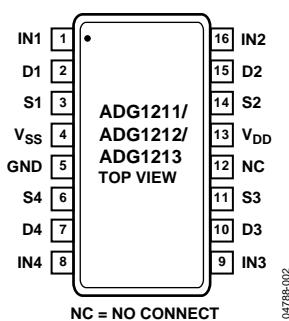


Figure 2. TSSOP Pin Configuration

ADG1211/ADG1212/ADG1213

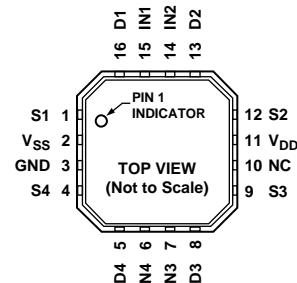


Figure 3. LFCSP Pin Configuration

Table 6. Pin Function Descriptions

Pin No.		Mnemonic	Description
TSSOP	LFCSP		
1	15	IN1	Logic Control Input.
2	16	D1	Drain Terminal. Can be an input or output.
3	1	S1	Source Terminal. Can be an input or output.
4	2	V _{SS}	Most Negative Power Supply Potential.
5	3	GND	Ground (0 V) Reference.
6	4	S4	Source Terminal. Can be an input or output.
7	5	D4	Drain Terminal. Can be an input or output.
8	6	IN4	Logic Control Input.
9	7	IN3	Logic Control Input.
10	8	D3	Drain Terminal. Can be an input or output.
11	9	S3	Source Terminal. Can be an input or output.
12	10	NC	No Connection.
13	11	V _{DD}	Most Positive Power Supply Potential.
14	12	S2	Source Terminal. Can be an input or output.
15	13	D2	Drain Terminal. Can be an input or output.
16	14	IN2	Logic Control Input.

TERMINOLOGY

I_{DD}

The positive supply current.

I_{SS}

The negative supply current.

V_D (V_S)

The analog voltage on Terminals D and S.

R_{ON}

The ohmic resistance between D and S.

R_{FLAT(ON)}

Flatness is defined as the difference between the maximum and minimum value of on resistance, as measured over the specified analog signal range.

I_S (Off)

The source leakage current with the switch off.

I_D (Off)

The drain leakage current with the switch off.

I_D, I_S (On)

The channel leakage current with the switch on.

V_{INL}

The maximum input voltage for Logic 0.

V_{INH}

The minimum input voltage for Logic 1.

I_{INL} (I_{INH})

The input current of the digital input.

C_S (Off)

The off switch source capacitance, measured with reference to ground.

C_D (Off)

The off switch drain capacitance, measured with reference to ground.

C_D, C_S (On)

The on switch capacitance, measured with reference to ground.

C_{IN}

The digital input capacitance.

t_{ON}

The delay between applying the digital control input and the output switching on. See Figure 23.

t_{OFF}

The delay between applying the digital control input and the output switching off. See Figure 23.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

Off Isolation

A measure of unwanted signal coupling through an off switch.

Crosstalk

A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

Bandwidth

The frequency at which the output is attenuated by 3 dB.

On Response

The frequency response of the on switch.

Insertion Loss

The loss due to the on resistance of the switch.

THD + N

The ratio of the harmonic amplitude plus noise of the signal to the fundamental.

TYPICAL PERFORMANCE CHARACTERISTICS

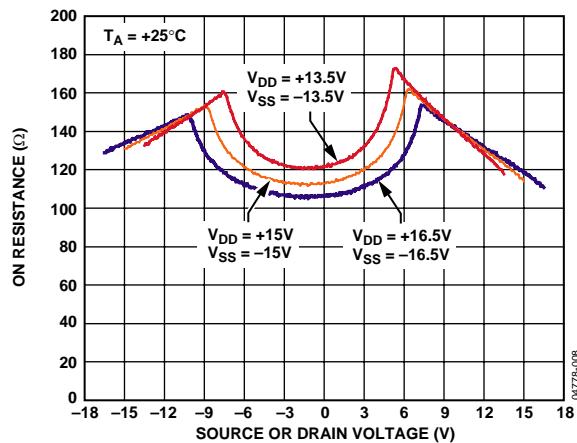


Figure 4. On Resistance as a Function of V_D (V_S) for Dual Supply

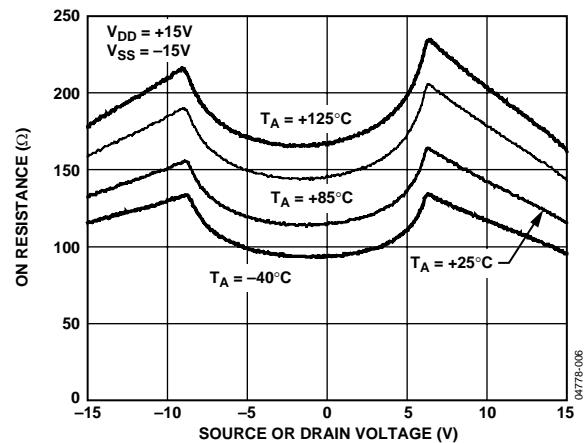


Figure 7. On Resistance as a Function of V_D (V_S) for Different Temperatures, Dual Supply

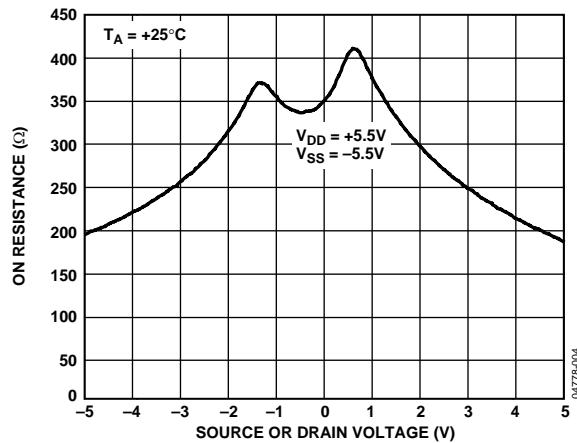


Figure 5. On Resistance as a Function of V_D (V_S) for Dual Supply

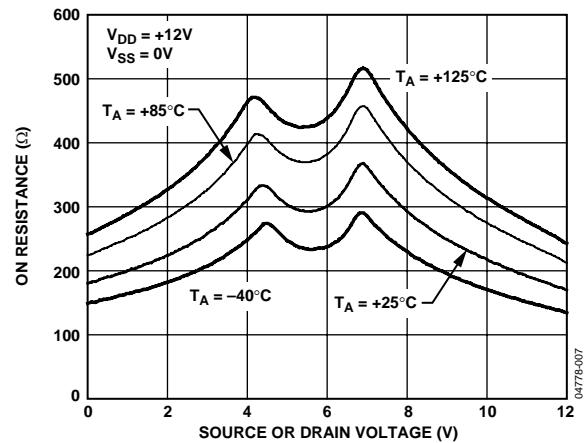


Figure 8. On Resistance as a Function of V_D (V_S) for Different Temperatures, Single Supply

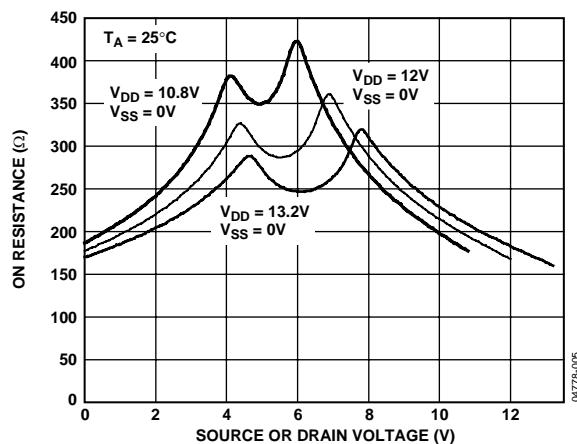


Figure 6. On Resistance as a Function of V_D (V_S) for Single Supply

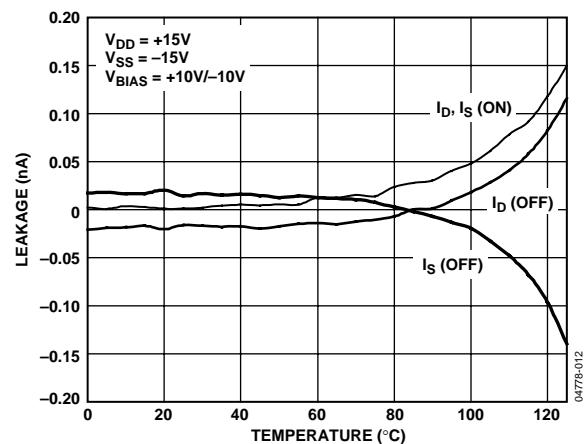


Figure 9. Leakage Currents as a Function of Temperature, Dual Supply

ADG1211/ADG1212/ADG1213

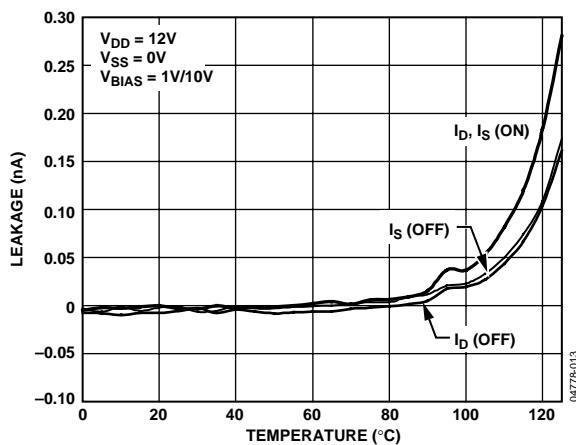


Figure 10. Leakage Currents as a Function of Temperature, Single Supply

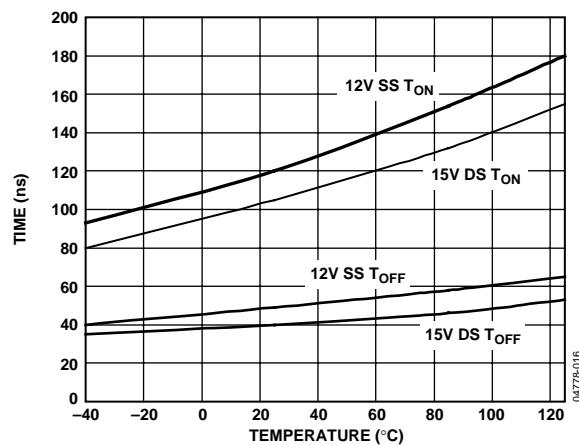


Figure 13. T_{on}/T_{off} Times vs. Temperature

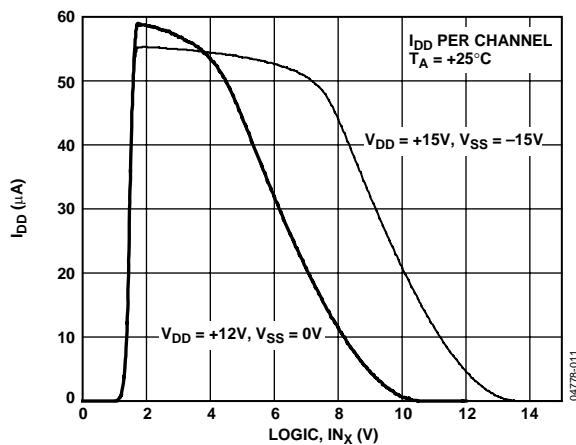


Figure 11. I_{DD} vs. Logic Level

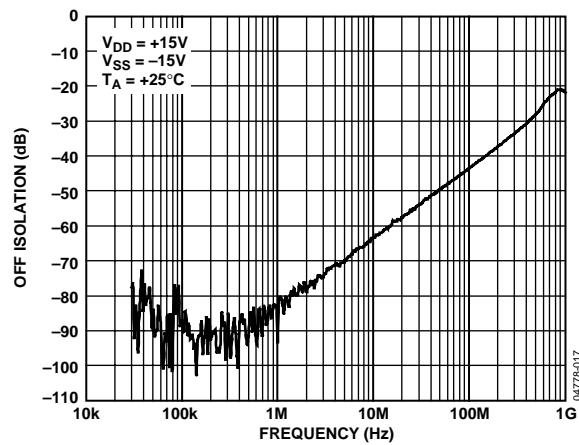


Figure 14. Off Isolation vs. Frequency

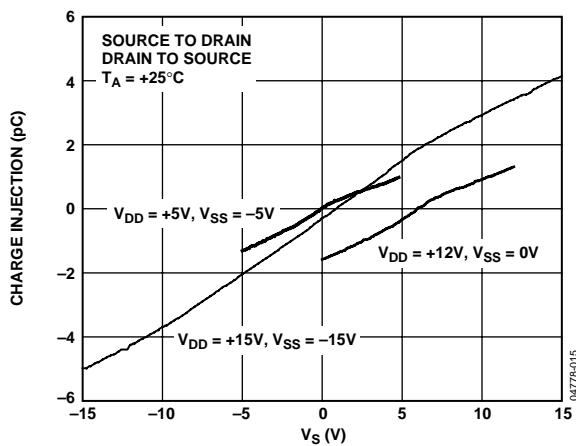


Figure 12. Charge Injection vs. Source Voltage

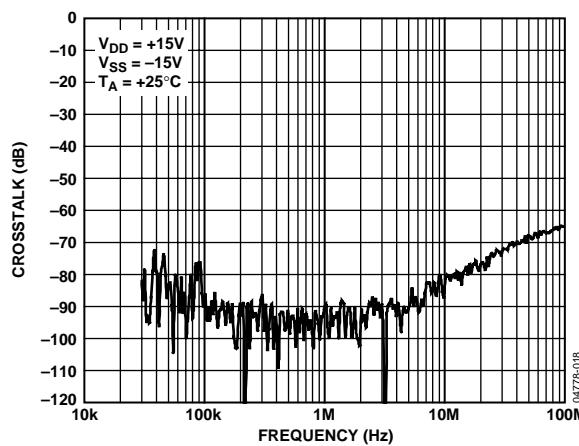


Figure 15. Crosstalk vs. Frequency

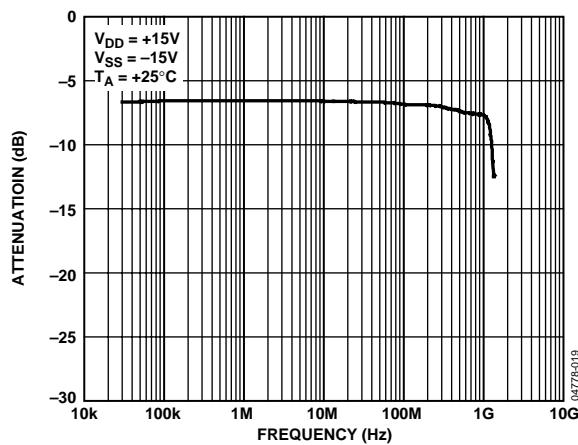


Figure 16. On Response vs. Frequency

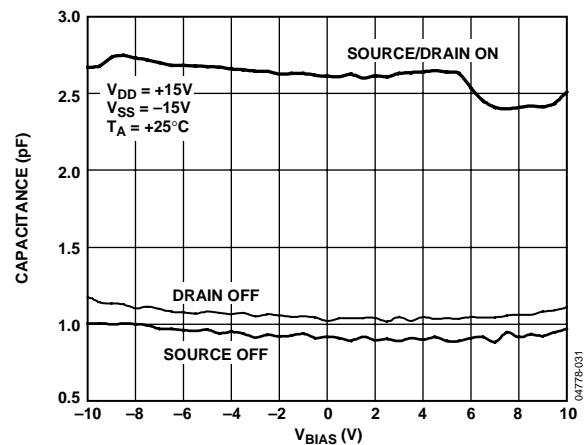


Figure 18. Capacitance vs. Source Voltage, Dual Supply

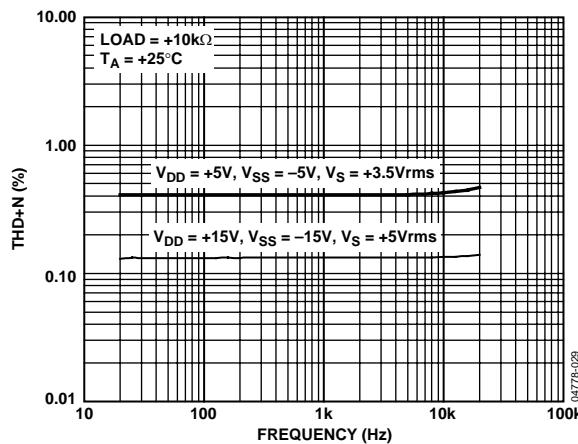


Figure 17. THD + N vs. Frequency

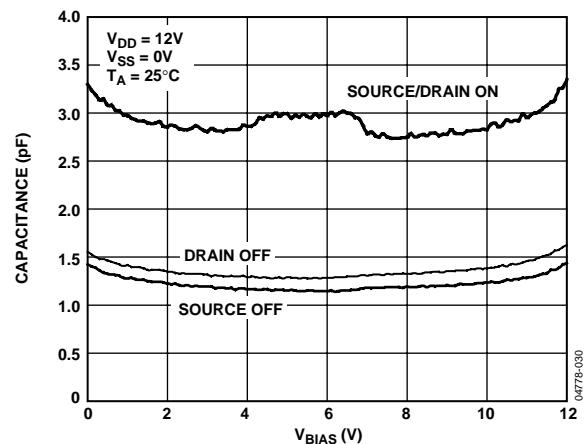


Figure 19. Capacitance vs. Source Voltage, Single Supply

ADG1211/ADG1212/ADG1213

TEST CIRCUITS

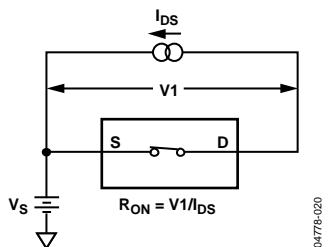


Figure 20. Test Circuit 1—On Resistance

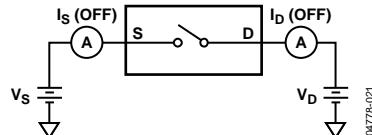


Figure 21. Test Circuit 2—Off Leakage

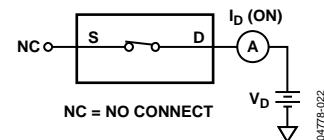


Figure 22. Test Circuit 3—On Leakage

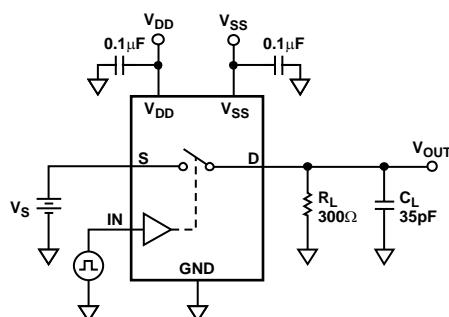


Figure 23. Test Circuit 4—Switching Times

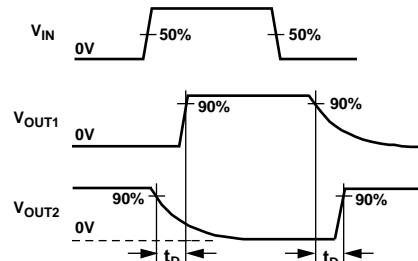
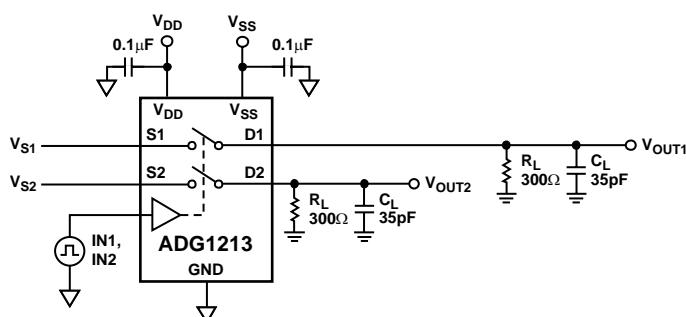
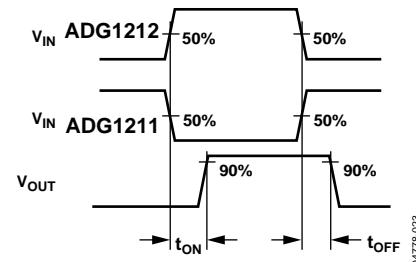


Figure 24. Test Circuit 5—Break-Before-Make Time Delay

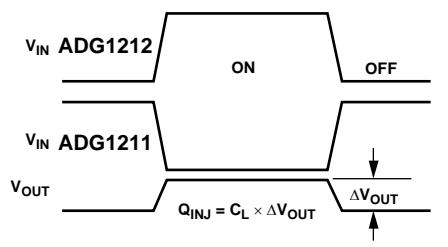
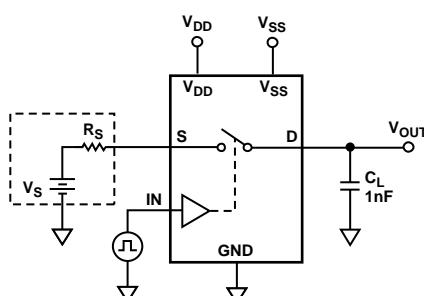


Figure 25. Test Circuit 6—Charge Injection

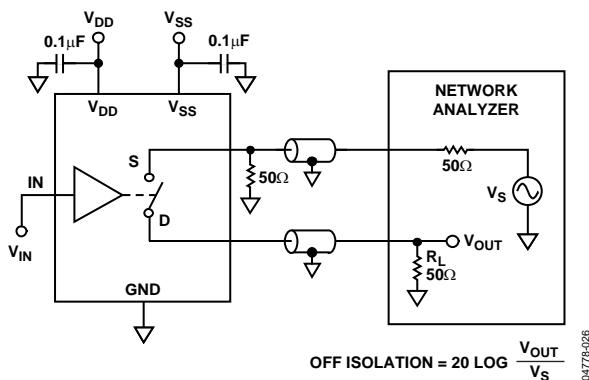


Figure 26. Test Circuit 7—Off Isolation

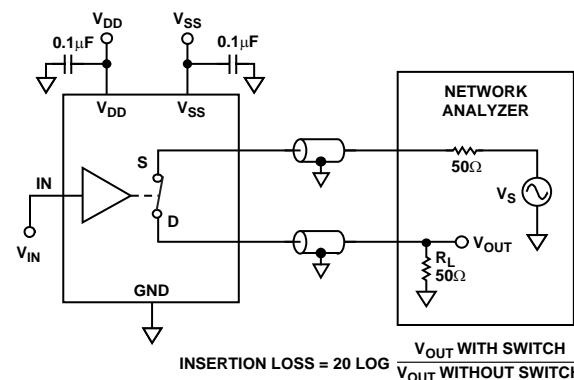


Figure 28. Test Circuit 9—Bandwidth

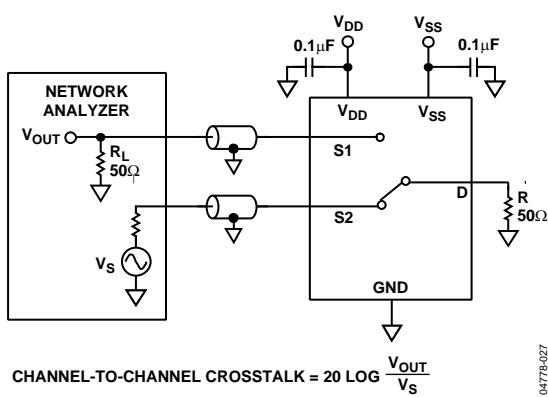


Figure 27. Test Circuit 8—Channel-to-Channel Crosstalk

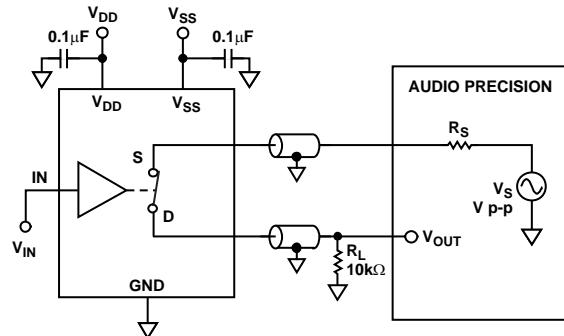
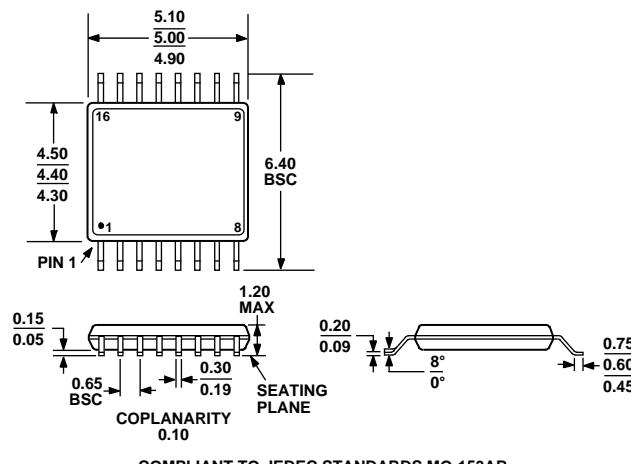


Figure 29. Test Circuit 10—THD + Noise

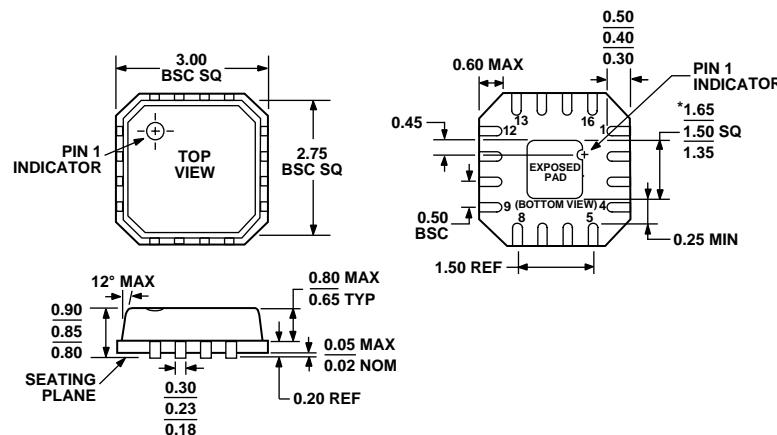
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153AB

Figure 30. 16-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-16)

Dimensions shown in millimeters



*COMPLIANT TO JEDEC STANDARDS MO-220-VEED-2
EXCEPT FOR EXPOSED PAD DIMENSION.

Figure 31. 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ]
3 mm × 3 mm Body, Very Thin Quad
(CP-16-3)

Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADG1211YRUZ ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1211YRUZ-REEL ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1211YRUZ-REEL7 ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1211YCPZ-500RL7 ¹	–40°C to +125°C	Lead Frame Chip Scale Package (LFCSP_VQ)	CP-16-3
ADG1211YCPZ-REEL7 ¹	–40°C to +125°C	Lead Frame Chip Scale Package (LFCSP_VQ)	CP-16-3
ADG1212YRUZ ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1212YRUZ-REEL ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1212YRUZ-REEL7 ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1212YCPZ-500RL7 ¹	–40°C to +125°C	Lead Frame Chip Scale Package (LFCSP_VQ)	CP-16-3
ADG1212YCPZ-REEL7 ¹	–40°C to +125°C	Lead Frame Chip Scale Package (LFCSP_VQ)	CP-16-3
ADG1213YRUZ ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1213YRUZ-REEL ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1213YRUZ-REEL7 ¹	–40°C to +125°C	Thin Shrink Small Outline Package (TSSOP)	RU-16
ADG1213YCPZ-500RL7 ¹	–40°C to +125°C	Lead Frame Chip Scale Package (LFCSP_VQ)	CP-16-3
ADG1213YCPZ-REEL7 ¹	–40°C to +125°C	Lead Frame Chip Scale Package (LFCSP_VQ)	CP-16-3

¹ Z = Pb-free part.

ADG1211/ADG1212/ADG1213

NOTES

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